

# Subject Name Solutions

1313202 – Winter 2023

Semester 1 Study Material

*Detailed Solutions and Explanations*

## Question 1(a) [3 marks]

Explain difference between Active and passive network.

### Solution

#### Active Network

Contains at least one energy source  
Can deliver power to other elements  
Examples: Transistors, Op-amps, Batteries

#### Passive Network

Contains no energy source  
Cannot deliver power to other elements  
Examples: Resistors, Capacitors, Inductors

### Mnemonic

“Active Adds Power, Passive Pulls Power”

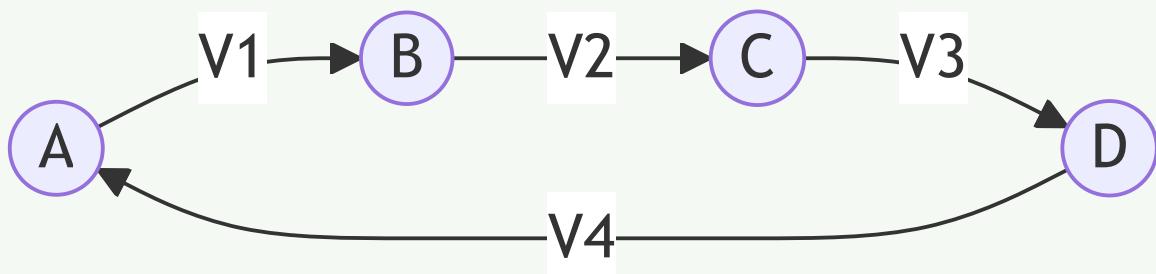
## Question 1(b) [4 marks]

State and explain Kirchhoff's voltage law (KVL).

### Solution

**Kirchhoff's Voltage Law (KVL):** The algebraic sum of all voltages around any closed path (loop) in a circuit is zero.

Diagram:



**Mathematical Form:**  $V_1 + V_2 + V_3 + V_4 = 0$

- **Circuit Application:** When moving around a loop, voltage rises (batteries) are positive and voltage drops (components) are negative
- **Physical Meaning:** Total energy in a closed loop is conserved

### Mnemonic

“Voltage Loop Sum Zero”

## Question 1(c) [7 marks]

Define the following terms: (1) Charge (2) Current (3) Potential (4) E.M.F. (5) Inductance (6) Capacitance (7) Frequency.

## Solution

Term	Definition
Charge	The basic electrical quantity measured in coulombs (C); flow of electrons creates electricity
Current	The rate of flow of electric charge, measured in amperes (A); $I = \frac{dQ}{dt}$
Potential	Electric potential energy per unit charge, measured in volts (V)
E.M.F.	Electromotive force, energy supplied by source per unit charge, measured in volts (V)
Inductance	Property of a conductor to oppose change in current, measured in henry (H)
Capacitance	Ability of a component to store electric charge, measured in farad (F)
Frequency	Number of cycles per second of an alternating quantity, measured in hertz (Hz)

## Mnemonic

“Careful Currents Pass Easily Into Circuit Frequently”

## Question 1(c) OR [7 marks]

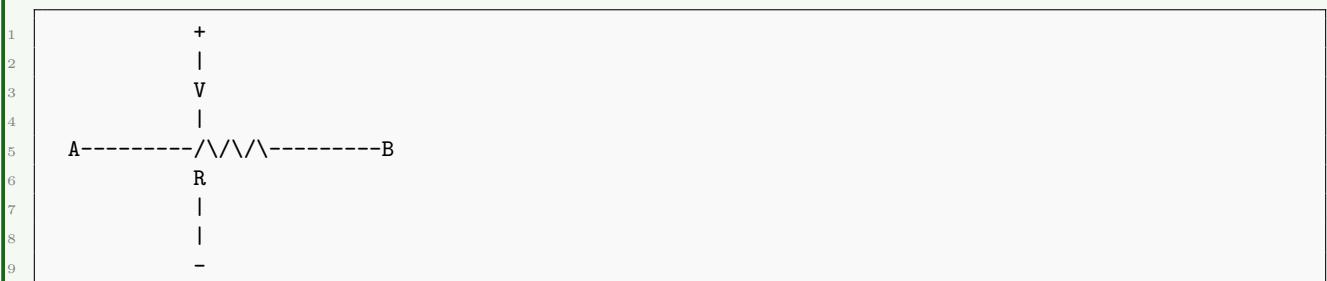
State Ohm's law. Write its application and limitation.

## Solution

**Ohm's Law:** The current flowing through a conductor is directly proportional to the potential difference across it and inversely proportional to its resistance.

**Mathematical Form:**  $I = V/R$

**Diagram:**



**Applications of Ohm's Law:**

- Computing current, voltage, resistance in circuits
- Design of electrical networks
- Power calculations ( $P = VI = I^2R = V^2/R$ )
- Voltage division and current division

**Limitations of Ohm's Law:**

- Not valid for non-linear elements (diodes, transistors)
- Not applicable at very high frequencies
- Not valid for non-metallic conductors like semiconductors
- Not applicable for vacuum tubes and gaseous devices

## Mnemonic

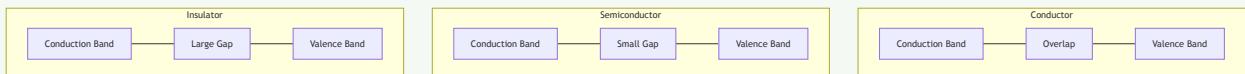
“Voltage Drives, Resistance Restricts”

## Question 2(a) [3 marks]

Draw and explain energy band diagrams for insulator, conductor and Semiconductor.

## Solution

### Energy Band Diagrams:



- **Conductor:** Valence and conduction bands overlap, allowing easy electron flow
- **Semiconductor:** Small energy gap (~1eV) between bands; electrons can jump with thermal energy
- **Insulator:** Large energy gap (>5eV) prevents electron movement between bands

## Mnemonic

“Conductors Connect, Semiconductors Sometimes, Insulators Impede”

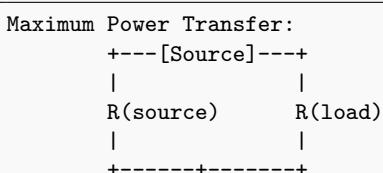
## Question 2(b) [4 marks]

Write statement of Maximum power transfer theorem and reciprocity theorem.

## Solution

Theorem	Statement
<b>Maximum Power Transfer Theorem</b>	Maximum power is transferred from source to load when load resistance equals the source internal resistance ( $R_L = R_S$ )
<b>Reciprocity Theorem</b>	In a linear passive network with a single source, if the source is moved from position A to B, the current at A due to source at B will equal the current at B when source was at A

## Diagram:



## Mnemonic

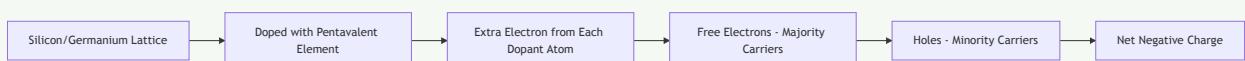
“Match Resistance to Maximize Power; Switch Source and Sink, Current Stays Same”

## Question 2(c) [7 marks]

Explain the formation and conduction of N-type materials.

## Solution

### N-type Semiconductor Formation:



- **Doping Process:** Silicon/Germanium (4 valence e<sup>-</sup>) doped with pentavalent elements (P, As, Sb)
- **Extra Electron:** Each dopant atom provides 1 extra electron after covalent bonding
- **Conduction Mechanism:**
  - **Majority Carriers:** Free electrons (negative charge carriers)
  - **Minority Carriers:** Holes (very few)
- **Electrical Properties:** Increased conductivity and negative charge carriers

## Mnemonic

“Pentavalent Provides Plus one Electron, Negative-type”

### Question 2(a) OR [3 marks]

Define valence band, conduction band and forbidden gap.

#### Solution

Term	Definition
<b>Valence Band</b>	The highest energy band filled with electrons, where electrons are bound to atoms
<b>Conduction Band</b>	The band above valence band where electrons move freely and contribute to electrical conduction
<b>Forbidden Gap</b>	The energy range between valence and conduction bands where no electron states exist

Diagram:



## Mnemonic

“Valence Holds, Forbidden Blocks, Conduction Flows”

### Question 2(b) OR [4 marks]

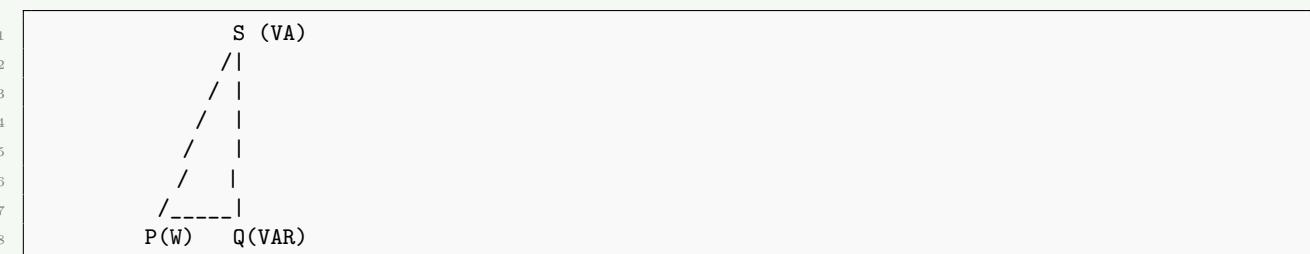
Define the terms active power, reactive power and power factor with power triangle.

#### Solution

Power Terms in AC Circuits:

Term	Definition
<b>Active Power (P)</b>	Actual power consumed, measured in watts (W); $P = VI \cos \theta$
<b>Reactive Power (Q)</b>	Power oscillating between source and load, measured in VAR; $Q = VI \sin \theta$
<b>Power Factor (PF)</b>	Ratio of active power to apparent power; $PF = \cos \theta$

Power Triangle:



- **Apparent Power (S):** Vector sum of active and reactive power
- **Power Triangle:** Right triangle with P, Q, and S as sides
- **Power Factor:**  $\cos \theta = P/S$  (0 to 1)

## Mnemonic

“Active Power Works, Reactive Power Waits”

### Question 2(c) OR [7 marks]

Explain the structure of atom of trivalent, tetravalent and pentavalent elements.

#### Solution

##### Atomic Structures:

Element Type	Valence Electrons	Examples	Electronic Configuration
Trivalent	3	Boron, Aluminum, Gallium	3 electrons in outermost shell
Tetravalent	4	Carbon, Silicon, Germanium	4 electrons in outermost shell
Pentavalent	5	Nitrogen, Phosphorus, Arsenic	5 electrons in outermost shell

##### Diagram:



- **Trivalent Elements:** Used as p-type dopants in semiconductors
- **Tetravalent Elements:** Form semiconductor base materials
- **Pentavalent Elements:** Used as n-type dopants in semiconductors

## Mnemonic

“Three Tries to Bond, Four Forms Full bonds, Five Frees an Electron”

### Question 3(a) [3 marks]

Draw the symbol of photodiode and state it's application.

#### Solution

##### Photodiode Symbol:



##### Applications of Photodiode:

- Light sensors and detectors
- Optical communication systems
- Camera exposure controls
- Barcode scanners
- Medical instruments
- Solar cells

## Mnemonic

“Photons Produce Current”

### Question 3(b) [4 marks]

Write a Short note on LED.

#### Solution

**LED (Light Emitting Diode):**

Parameter	Description
<b>Structure</b>	p-n junction with special doping materials
<b>Working</b>	Electrons recombine with holes, releasing energy as photons
<b>Materials</b>	GaAs (red), GaP (green), GaN (blue), etc.
<b>Voltage</b>	Forward voltage typically 1.8V to 3.3V depending on color

#### Advantages:

- High efficiency (low power consumption)
- Long life (50,000+ hours)
- Small size and durability
- Various colors available

#### Applications:

- Indicators and displays
- Lighting systems
- TV/monitor backlights
- Traffic signals

#### Mnemonic

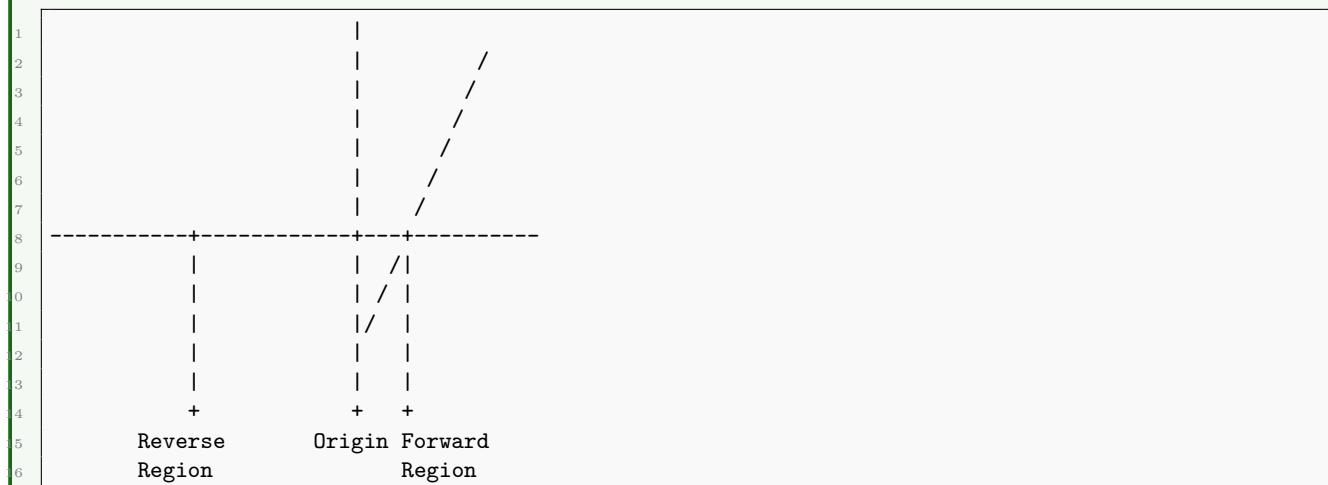
“Light Emits when Diode conducts”

### Question 3(c) [7 marks]

Draw and explain VI characteristic of PN junction diode.

#### Solution

**P-N Junction Diode V-I Characteristic:**



#### Forward Bias Region:

- **Knee Voltage:** 0.3V (Ge), 0.7V (Si) where current starts flowing
- **Current Equation:**  $I = I_s(e^{(qV/kT)} - 1)$
- **Conductivity:** High (low resistance)

#### Reverse Bias Region:

- **Leakage Current:** Very small reverse current (micro-amps)
- **Breakdown Region:** Sharp increase in current at breakdown voltage

- **Conductivity:** Very low (high resistance)

**Key Points:**

- **Barrier Potential:** Decreases in forward bias, increases in reverse bias
- **Diode Resistance:** Dynamic resistance changes with applied voltage
- **Temperature Effect:** Voltage drop decreases with temperature increase

**Mnemonic**

“Forward Flows Freely, Reverse Resists”

**Question 3(a) OR [3 marks]**

List the applications of PN junction diode.

**Solution**

**Applications of PN Junction Diode:**

Application Category	Examples
Rectification	Half-wave rectifier, Full-wave rectifier, Bridge rectifier
Signal Processing	Signal demodulation, Clipping circuits, Clamping circuits
Protection	Voltage spike protection, Reverse polarity protection
Logic Gates	Diode logic circuits, Switching applications
Voltage Regulation	Zener diodes for voltage references
Light Applications	LEDs, Photodiodes, Solar cells

**Mnemonic**

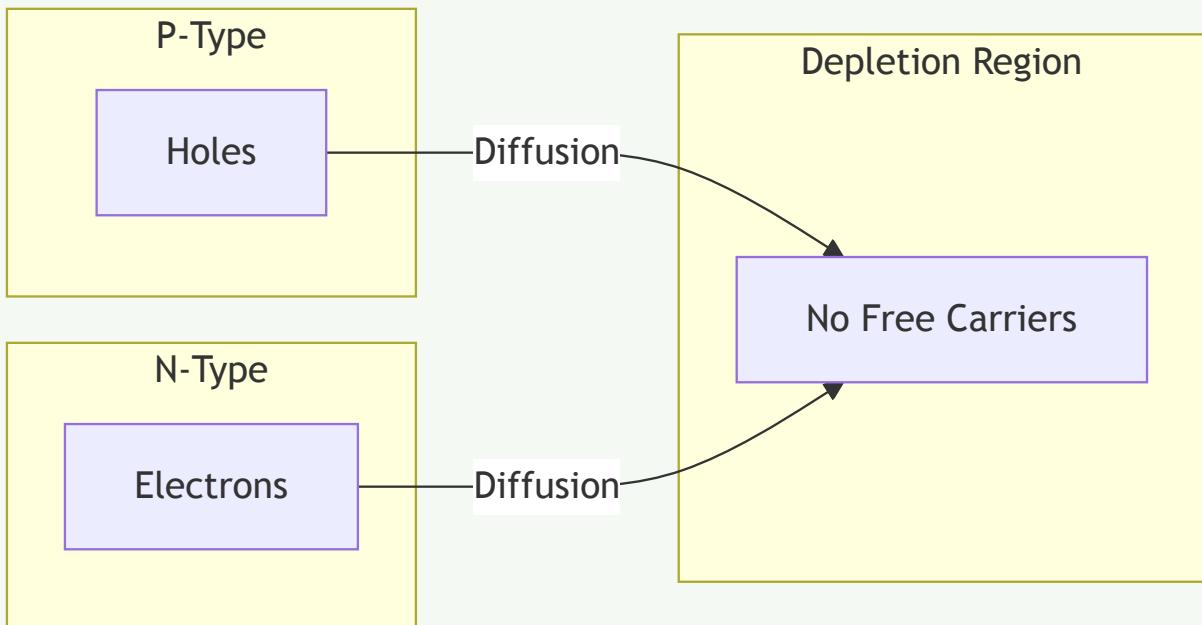
“Rectify, Process, Protect, Logic, Regulate, Light”

**Question 3(b) OR [4 marks]**

Explain the formation of depletion region in unbiased P-N junction.

**Solution**

**Depletion Region Formation:**



### Process:

- **Diffusion:** Electrons from n-side diffuse to p-side; holes from p-side diffuse to n-side
  - **Recombination:** Electrons and holes recombine at the junction
  - **Immobile Ions:** Exposed positive ions in n-region, negative ions in p-region
  - **Electric Field:** Forms between positive and negative ions, opposing further diffusion
  - **Equilibrium:** Diffusion current equals drift current; no net current flows

### **Properties of Depletion Region:**

- No free charge carriers
  - Acts as insulator
  - Width depends on doping levels
  - Contains built-in potential barrier

## Mnemonic

“Diffusion Depletes Carriers, Creating Electric barrier”

### Question 3(c) OR [7 marks]

Explain construction, working and applications of PN junction diode.

### Solution

### **Construction of PN Junction Diode:**

The diagram illustrates a P-N junction diode. It features two vertical columns of atoms: a 'P-Type' column on the left and an 'N-Type' column on the right, separated by a thin boundary. Each column is surrounded by a shaded 'Depletion' region, which is further divided into three distinct 'Region' sections at the bottom.

- **P-Type Region:** Silicon/Germanium doped with trivalent impurities (boron, aluminum)
  - **N-Type Region:** Silicon/Germanium doped with pentavalent impurities (phosphorus, arsenic)
  - **Junction:** Interface between p and n regions with depletion layer
  - **Terminals:** Anode (p-side) and Cathode (n-side)

### • Terminals. And Working Principle:

Bias Condition	Behavior
Forward Bias	Depletion region narrows, current flows when $V > 0.7V$ (Si)
Reverse Bias	Depletion region widens, only small leakage current flows

#### Applications:

- Rectification in power supplies
- Signal demodulation in radios
- Voltage regulation (Zener)
- Signal clipping and clamping
- Logic gates and switching
- Light emission and detection

#### Mnemonic

“Forward Flow, Reverse Restrict, Convert AC to DC”

### Question 4(a) [3 marks]

Define: (1) Ripple frequency (2) Ripple factor (3) PIV of a diode.

#### Solution

Term	Definition
Ripple Frequency	The frequency of AC component present in rectified DC output; for half-wave $f = \text{supply frequency}$ , for full-wave $f = 2 \times \text{supply frequency}$
Ripple Factor ( )	Ratio of RMS value of AC component to DC component in rectifier output; $= V_{ac(rms)} / V_{dc}$
PIV of Diode	Peak Inverse Voltage - maximum reverse voltage a diode can withstand without breakdown

#### Mnemonic

“Ripples Per second, Ripple Proportion, Reverse Peak Voltage”

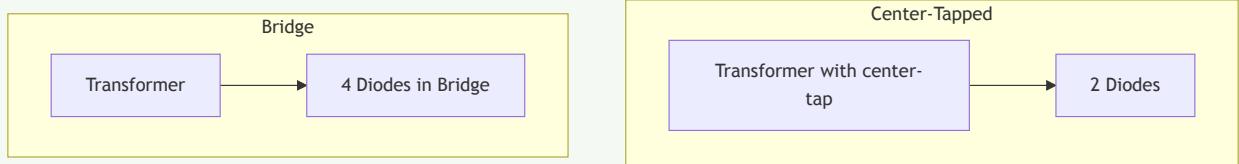
### Question 4(b) [4 marks]

Give comparison between full wave rectifier with two diodes and full wave bridge rectifier.

#### Solution

Parameter	Center-Tapped Full Wave	Bridge Rectifier
Diodes Used	2 diodes	4 diodes
Transformer	Center-tapped required	No center tap needed
PIV of Diode	$2V_m$	$V_m$
Output Voltage	$V_{dc} = 0.637V_m$	$V_{dc} = 0.637V_m$
Ripple Factor	0.48	0.48
Efficiency	81.2%	81.2%
TUF	0.693	0.693

### Diagram:



### Mnemonic

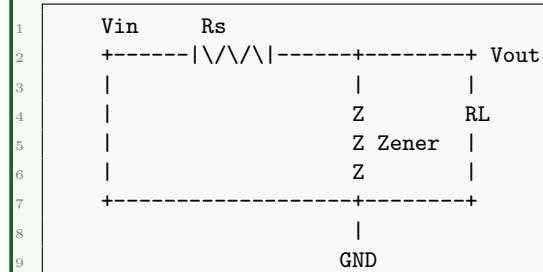
“Bridge Beats Tap with Lower PIV but Needs More Diodes”

## Question 4(c) [7 marks]

Explain zener diode as voltage regulator.

### Solution

#### Zener Diode Voltage Regulator:



#### Working Principle:

- **Reverse Biased:** Zener operates in breakdown region
- **Constant Voltage:** Maintains fixed voltage ( $V_z$ ) across its terminals
- **Current Regulation:** Series resistor ( $R_s$ ) limits current
- **Load Changes:** When load current changes, Zener current changes to maintain constant output voltage

#### Design Equations:

- $R_s = (V_{in} - V_z) / (I_L + I_z)$
- Power rating of Zener:  $P_z = V_z \times I_z(\max)$

#### Advantages:

- Simple circuit
- Low cost
- Good regulation for small loads
- Fast response to load changes

#### Limitations:

- Power wastage in  $R_s$  and Zener
- Limited output current capability
- Temperature dependence of  $V_z$

### Mnemonic

“Zener Stays at breakdown Voltage despite Current changes”

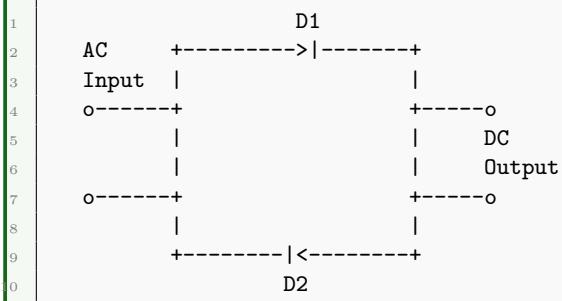
## Question 4(a) OR [3 marks]

What is rectifier? Explain full wave rectifier with waveforms.

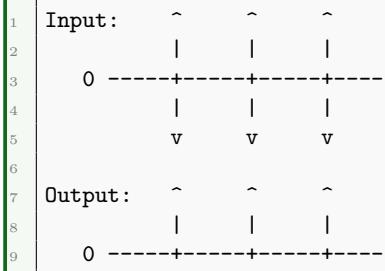
### Solution

**Rectifier:** A circuit that converts AC voltage to pulsating DC voltage by allowing current flow in one direction only.

#### Full Wave Rectifier:



### Waveforms:



- **Operation:** Both half cycles of AC input are converted to same polarity
- **Frequency:** Output ripple frequency is twice the input frequency
- **Voltage:**  $V_{dc} = 0.637V_m$  (where  $V_m$  is peak input voltage)

### Mnemonic

“Full Wave Forms Full Output”

## Question 4(b) OR [4 marks]

Why filter is required in rectifier? State the different types of filter and explain any one type of filter.

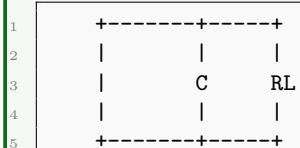
### Solution

**Need for Filters:** Rectifiers produce pulsating DC with large ripples; filters smooth this output to provide steady DC voltage.

#### Types of Filters:

- Capacitor (C) filter
- Inductor (L) filter
- LC filter
- (Pi) filter
- RC filter

#### Capacitor Filter:



#### Working:

- Capacitor charges during voltage rise
- Discharges slowly through load during voltage fall
- Acts as temporary storage element
- Time constant RC determines discharge rate
- Reduces ripple by providing discharge path

#### Advantages:

- Simple and economical
- Good smoothing for light loads
- Increases DC output voltage

## Mnemonic

“Capacitor Catches Charge and Releases Slowly”

### Question 4(c) OR [7 marks]

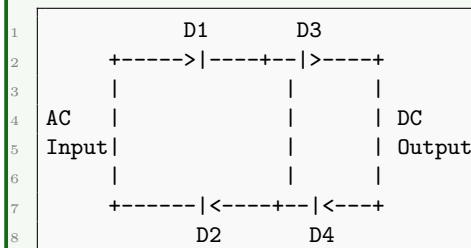
Write the need of rectifier. Explain bridge rectifier with circuit diagram and draw its input and output waveforms.

## Solution

### Need for Rectifiers:

- Convert AC to DC for electronic devices
- Power supplies for DC-operated equipment
- Battery charging circuits
- DC power for industrial drives
- Signal demodulation in communication

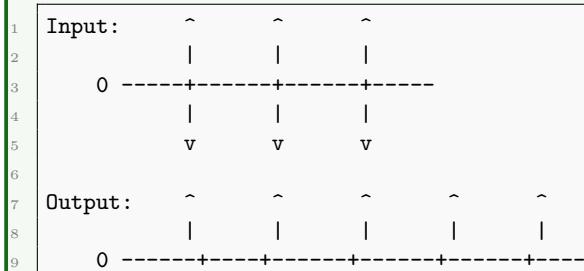
### Bridge Rectifier Circuit:



### Working Principle:

- **Positive Half Cycle:** D1 and D4 conduct, D2 and D3 block
- **Negative Half Cycle:** D2 and D3 conduct, D1 and D4 block
- **Both Half Cycles:** Current flows in same direction through load

### Input-Output Waveforms:



### Characteristics:

- $V_{dc} = 0.637V_m$  ( $V_m$ : peak input voltage)
- PIV of each diode =  $V_m$
- Ripple factor = 0.48
- Efficiency = 81.2%
- TUF = 0.693

## Mnemonic

“Bridge Brings Both halves to Direct Current”

### Question 5(a) [3 marks]

Explain causes of electronic waste.

## Solution

### Causes of Electronic Waste:

Cause	Description
Rapid Technology Change	Frequent upgrades and obsolescence of electronics
Short Lifecycle	Devices designed with limited useful life
Consumer Behavior	Preference for new gadgets over repair
Manufacturing Issues	Poor quality leading to early failures
Economic Factors	Sometimes cheaper to replace than repair
Marketing Strategies	Promoting new models through planned obsolescence

### Mnemonic

“Upgrade, Use, Throw, Repeat”

## Question 5(b) [4 marks]

Compare PNP and NPN transistors.

### Solution

Parameter	PNP Transistor	NPN Transistor
Symbol		
Current Flow	Emitter to Collector	Collector to Emitter
Majority Carriers	Holes	Electrons
Biassing	Emitter positive, Collector negative	Collector positive, Emitter negative
Switching Speed	Slower	Faster
Usage	Less common	More common

### Mnemonic

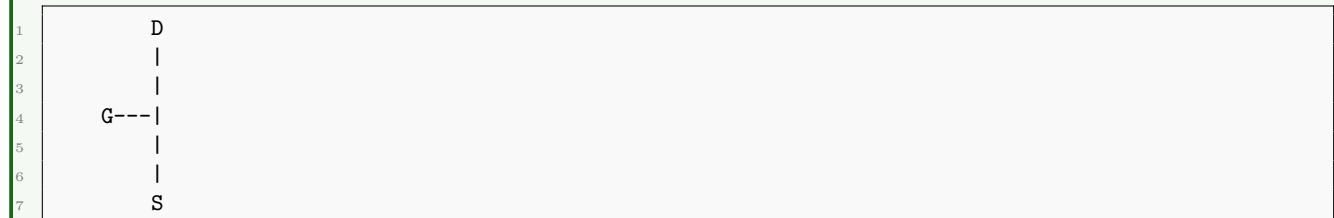
“PNP: Positive to Negative to Positive; NPN: Negative to Positive to Negative”

## Question 5(c) [7 marks]

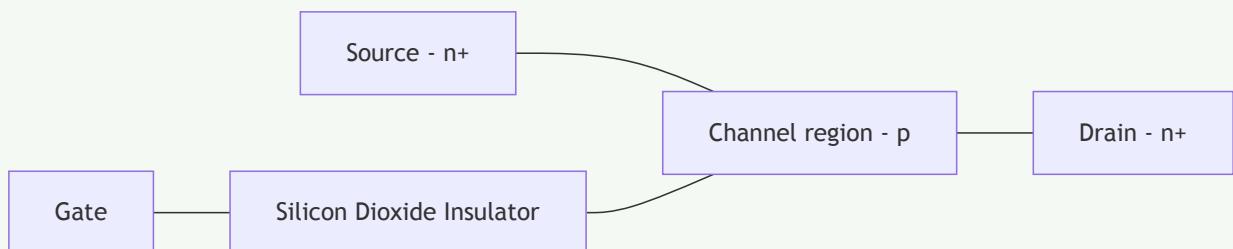
Draw the symbol, explain the construction and working of MOSFET.

### Solution

MOSFET Symbol (N-Channel Enhancement):



Construction:



Components:

- **Substrate:** P-type semiconductor body
- **Source/Drain:** Heavily doped n+ regions

- **Gate:** Metal electrode separated by insulator ( $\text{SiO}_2$ )
- **Channel:** Forms between source and drain when biased

#### Working Principle:

- **Enhancement Mode:** No channel exists initially; gate voltage creates channel
- **Threshold Voltage (VT):** Minimum gate voltage needed to form channel
- **Conducting State:** When  $V_{GS} > VT$ , electrons form channel, allowing current flow
- **Saturation Region:** Current remains constant despite increase in  $V_{DS}$
- **Linear Region:** Current proportional to  $V_{DS}$  at low drain voltages

#### Applications:

- Digital circuits (logic gates)
- Power amplifiers
- Switching applications
- Memory devices

#### Mnemonic

“Gate Voltage Controls Electron Channel”

### Question 5(a) OR [3 marks]

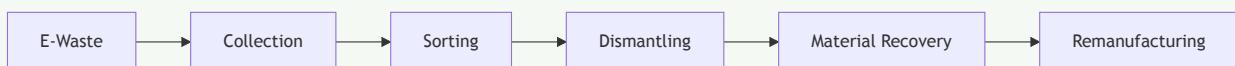
Explain methods to handle electronic waste.

#### Solution

#### Methods to Handle Electronic Waste:

Method	Description
<b>Reduce</b>	Designing products with longer lifecycle and upgradability
<b>Reuse</b>	Refurbishing and donating electronics for secondary use
<b>Recycle</b>	Systematic disassembly to recover valuable materials
<b>Responsible Disposal</b>	Proper collection and processing by certified facilities
<b>Extended Producer Responsibility</b>	Manufacturers take back used products
<b>Urban Mining</b>	Recovering precious metals from discarded electronics

#### Diagram:



#### Mnemonic

“Reduce, Reuse, Recycle, Recover Resources”

### Question 5(b) OR [4 marks]

Derive the relationship between  $dc$  and  $dc$ .

#### Solution

#### Relationship between $dc$ and $dc$ :

Given:

- $dc = IC/IE$  (Common base current gain)
- $dc = IC/IB$  (Common emitter current gain)

**Derivation:** From Kirchhoff's current law:  $IE = IC + IB$

Dividing both sides by  $IC$ :  $IE/IC = 1 + IB/IC$

Since  $dc = IC/IE$ :  $1/dc = 1 + IB/IC$

Since  $dc = IC/IB$ :  $1/dc = 1 + 1/dc$

**Final Relations:**

- $dc = dc/(1 + dc)$

- $dc = dc/(1 - dc)$

Table:	Value	Value	.....	.....	0.9	9	0.95	19	0.99	99
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## Mnemonic

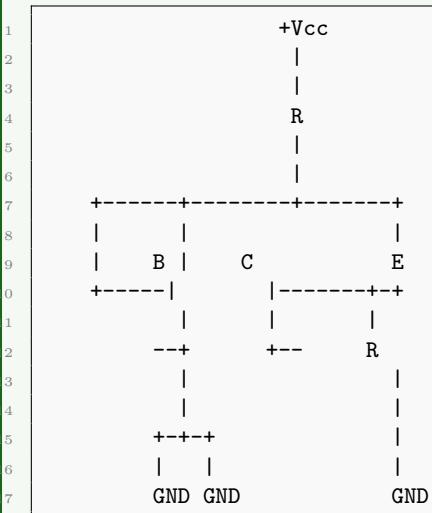
“Alpha approaches One as Beta approaches Infinity”

### Question 5(c) OR [7 marks]

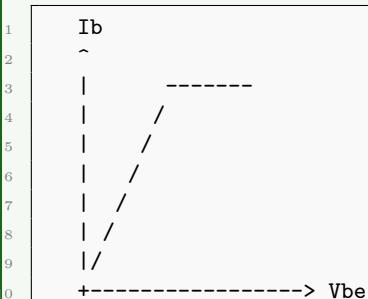
Explain common collector configuration with its input and output characteristics.

#### Solution

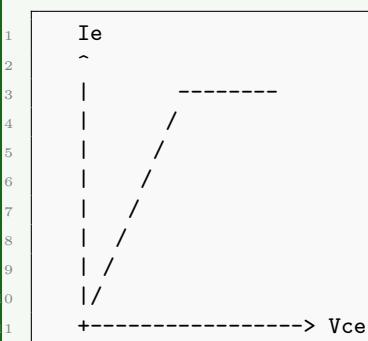
##### Common Collector (Emitter Follower) Configuration:



##### Input Characteristics:



##### Output Characteristics:



##### Key Features:

- Voltage Gain (Av):** Approximately 1 (unity)
- Current Gain (Ai):** High ( $+1$ )
- Input Impedance:** High ( $\times RE$ )
- Output Impedance:** Low ( $1/gm$ ) where  $gm$  is transconductance
- Phase Relationship:** No phase inversion between input and output

- **Applications:** Impedance matching, buffers, voltage regulators

**Characteristics:**

- **Input Resistance:**  $R_i = \frac{1}{2} \times (r_e + R_L)$
- **Output Resistance:**  $R_o = (r_s + r_e)/(1 + \beta) \approx 1$
- **Voltage Gain:**  $A_v = R_L/(R_L + r_e) \approx 1$
- **Current Gain:**  $A_i = \beta(1 + \beta)$

**Advantages:**

- Very high input impedance
- Low output impedance
- Good impedance matching properties
- No phase inversion

**Limitations:**

- No voltage gain (slightly less than 1)
- Used only for impedance matching

### Mnemonic

“Collector Common, Current amplifies, Voltage follows”

This completes the full solutions for the Elements of Electrical & Electronics Engineering (1313202) Winter 2023 examination.